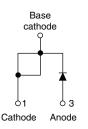


Vishay Semiconductors

Schottky Rectifier, 20 A





| PRODUCT SUMMARY | | | | | | | | |
|----------------------------------|----------------------|--|--|--|--|--|--|--|
| Package | TO-220AC | | | | | | | |
| I _{F(AV)} | 20 A | | | | | | | |
| V _R | 15 V | | | | | | | |
| V _F at I _F | See Electrical table | | | | | | | |
| I _{RM} max. | 600 mA at 100 °C | | | | | | | |
| T _J max. | 125 °C | | | | | | | |
| Diode variation | Single die | | | | | | | |
| E _{AS} | 10 mJ | | | | | | | |

FEATURES

- 125 °C T_J operation ($V_R < 5 V$)
- · Optimized for OR-ing applications
- Ultra low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability



RoHS

COMPLIANT

FREE

- High purity, high temperature epoxy HALOGEN for enhanced mechanical encapsulation strength and moisture resistance
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The Schottky rectifier module has been optimized for ultra low forward voltage drop specifically for the OR-ing of parallel power supplies. The proprietary barrier technology allows for reliable operation up to 125 °C junction temperature. Typical applications are in parallel switching power supplies, converters, reverse battery protection, and redundant power subsystems.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | | | |
|-----------------------------------|--|-------------|-------|--|--|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | | | |
| I _{F(AV)} | Rectangular waveform | 20 | A | | | | | | |
| V _{RRM} | | 15 | V | | | | | | |
| I _{FSM} | t _p = 5 μs sine | 700 | А | | | | | | |
| V _F | 19 A _{pk} , T _J = 125 °C (typical) | 0.25 | V | | | | | | |
| TJ | Range | - 55 to 125 | °C | | | | | | |

| VOLTAGE RATINGS | | | | | | | | |
|--------------------------------------|-------------------------|----|------------------|-------|--|--|--|--|
| PARAMETER | SYMBOL VS-STPS20L15DPbF | | VS-STPS20L15D-N3 | UNITS | | | | |
| Maximum DC reverse voltage | V _R | 15 | 15 | V | | | | |
| Maximum working peak reverse voltage | V _{RWM} | 15 | 0 | v | | | | |

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | |
|--|--------------------|--|---|--------|-------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CON | DITIONS | VALUES | UNITS | | | | |
| Maximum average forward current See fig. 5 | I _{F(AV)} | 50 % duty cycle, $T_C = 85 \ ^\circ C$, r | 20 | А | | | | | |
| Maximum peak one cycle non-repetitive surge current | | 5 μs sine or 3 μs rect. pulse | Following any rated load condition and with rated | 700 | А | | | | |
| See fig. 7 | IFSM | 10 ms sine or 6 ms rect. pulse | V _{RRM} applied | 330 | ~ | | | | |
| Non-repetitive avalanche energy | E _{AS} | T _J = 25 °C, I _{AS} = 2 A, L = 6 mH | 10 | mJ | | | | | |
| Repetitive avalanche current | I _{AR} | Current decaying linearly to ze Frequency limited by T _J maxir | 2 | А | | | | | |

Revision: 30-Aug-11

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| ELECTRICAL SPECIFICATIONS | | | | | | | | | |
|------------------------------------|--------------------------------|-----------------------------------|---------------------------------|------|------|------|--|--|--|
| PARAMETER | SYMBOL | TEST CO | TEST CONDITIONS | | | | | | |
| Forward voltage drop See fig. 1 | | 19 A | T, = 25 °C | - | 0.41 | | | | |
| | V _{EM} ⁽¹⁾ | 40 A | 1j=25 0 | - | 0.52 | v | | | |
| | V FM (** | 19 A | T,₁ = 125 °C | 0.25 | 0.33 | | | | |
| | | 40 A | 1j = 125 C | 0.37 | 0.50 | | | | |
| Reverse leakage current | I _{BM} ⁽¹⁾ | T _J = 25 °C | $V_{\rm B}$ = Rated $V_{\rm B}$ | - | 10 | mA | | | |
| See fig. 2 | 'RM \'' | T _J = 100 °C | VR - nateu VR | - | 600 | IIIA | | | |
| Threshold voltage | V _{F(TO)} | V _{F(TO)} 0.182 | | 182 | V | | | | |
| Forward slope resistance | r _t | i j = i j maximum | $T_J = T_J$ maximum | | | | | | |
| Maximum junction capacitance | CT | $V_R = 5 V_{DC}$ (test signal rar | - | 2000 | pF | | | | |
| Typical series inductance | L _S | Measured lead to lead 5 r | 8 | - | nH | | | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | | 10 | 000 | V/µs | | | |

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

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| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | | |
|---|-------------------|---|-------------|------------|--|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | | |
| Maximum junction temperature range | TJ | | - 55 to 125 | °C | | | | | |
| Maximum storage temperature range | T _{Stg} | | - 55 to 150 | | | | | | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation See fig. 4 | 1.5 | | | | | | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth and greased (for TO-220) | 0.50 | °C/W | | | | | |
| Maximum thermal resistance, junction to ambient | R _{thJA} | DC operation (for D ² PAK) | 40 | | | | | | |
| Approvimate weight | | | 2 | g | | | | | |
| Approximate weight | | | 0.07 | oz. | | | | | |
| Mounting torque | | Non-lubricated threads | 6 (5) | kgf · cm | | | | | |
| Mounting torque maximum | | Non-hubricateu trireaus | 12 (10) | (lbf ⋅ in) | | | | | |
| Marking device | | Case style TO-220AC | STPS20L15D | | | | | | |



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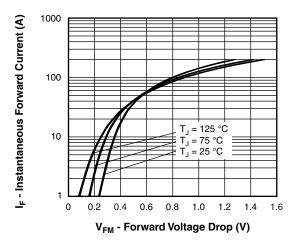


Fig. 1 - Maximum Forward Voltage Drop Characteristics

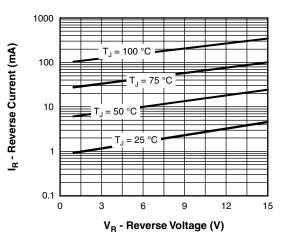


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

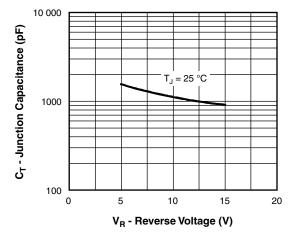
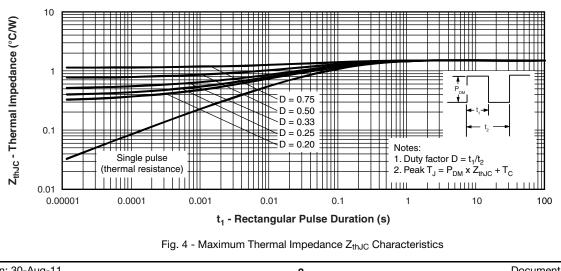


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

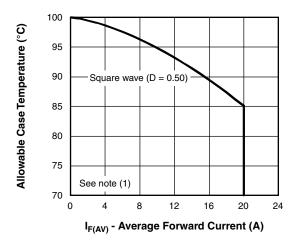


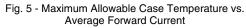
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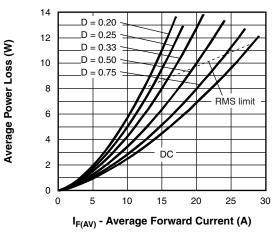
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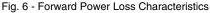


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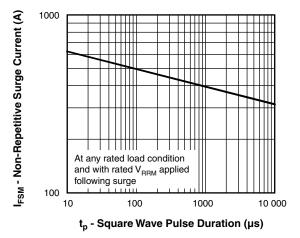


Fig. 7 - Maximum Non-Repetitive Surge Current

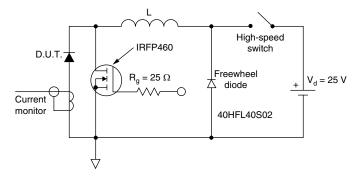


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6);

 Pd_{REV} = Inverse power loss = $V_{R1} \times I_R (1 - D)$; I_R at V_{R1} = 80 % rated V_R

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Vishay Semiconductors

ORDERING INFORMATION TABLE

| Device code | VS- | STPS | 20 | L | 15 | D | PbF | | | |
|-------------|-------------------|--------------------------------|---------|-----------------------|----|--------|---------|--|--|--|
| | | 2 | 3 | 4 | 5 | 6 | 7 | | | |
| | 1 · 2 · 3 · | 3 - Current rating (20 = 20 A) | | | | | | | | |
| | 5 | | - | ng (15 = al part n | - | | | | | |
| | 7 | - Env | ironmer | ntal digit ad (Pb) | | d RoHS | complia | | | |
| | | | | | | | | | | |

• -N3 = Halogen-free, RoHS compliant, and totally lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | |
| VS-STPS20L15DPbF | 50 | 1000 | Antistatic plastic tube | | | | | |
| VS-STPS20L15D-N3 | 50 | 1000 | Antistatic plastic tube | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | | |
|----------------------------|--------------|--------------------------|--|--|--|--|--|
| Dimensions | | www.vishay.com/doc?95221 | | | | | |
| Part marking information | TO-220AC PbF | www.vishay.com/doc?95224 | | | | | |
| | TO-220AC -N3 | www.vishay.com/doc?95068 | | | | | |
| SPICE model | | www.vishay.com/doc?95305 | | | | | |



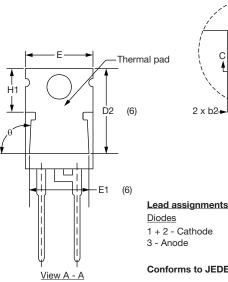
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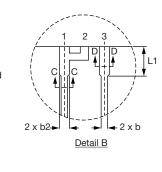
TO-220AC

plane

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

| SYMBOL | MILLIM | IETERS | INC | HES | NOTES | SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|--------|--------|--------|-------|-------|-------|----------|--------|--------|-------|-------|-------|
| STMBUL | MIN. | MAX. | MIN. | MAX. | NOTES | STIVIDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.25 | 4.65 | 0.167 | 0.183 | | E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | | E2 | - | 0.76 | - | 0.030 | 7 |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | | е | 2.41 | 2.67 | 0.095 | 0.105 | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | | e1 | 4.88 | 5.28 | 0.192 | 0.208 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 | H1 | 6.09 | 6.48 | 0.240 | 0.255 | 6, 7 |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | | L | 13.52 | 14.02 | 0.532 | 0.552 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 |
| С | 0.36 | 0.61 | 0.014 | 0.024 | | L3 | 1.78 | 2.13 | 0.070 | 0.084 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 | L4 | 0.76 | 1.27 | 0.030 | 0.050 | 2 |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 | ØΡ | 3.54 | 3.73 | 0.139 | 0.147 | |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | | Q | 2.60 | 3.00 | 0.102 | 0.118 | |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 | θ | 90° t | o 93° | 90° t | o 93° | |
| E | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 | | | | | | |

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- ⁽⁴⁾ Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline

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